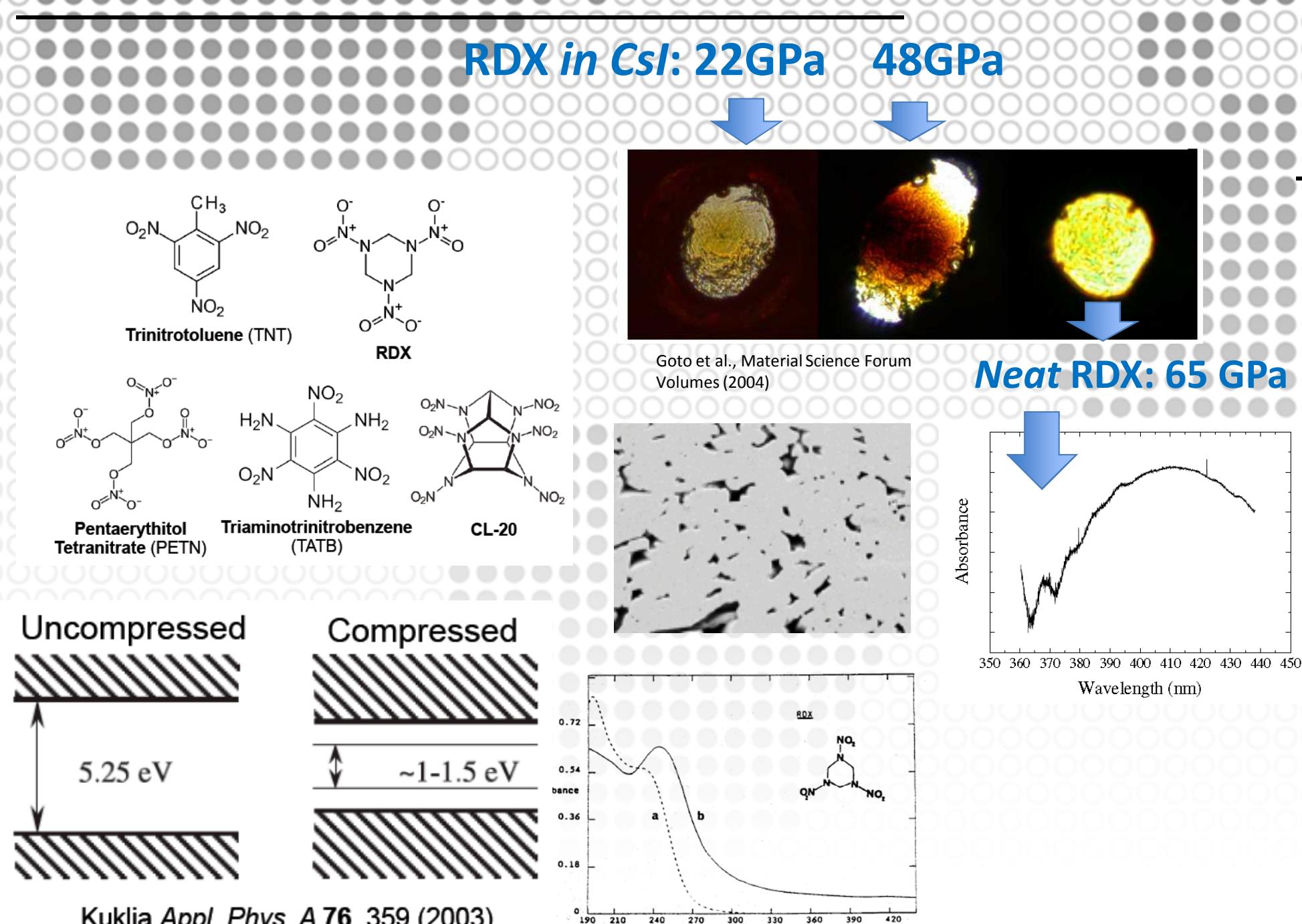


Measuring and modeling the electronic structure of explosives at the explosive/air interface.

SAND2016-5093C

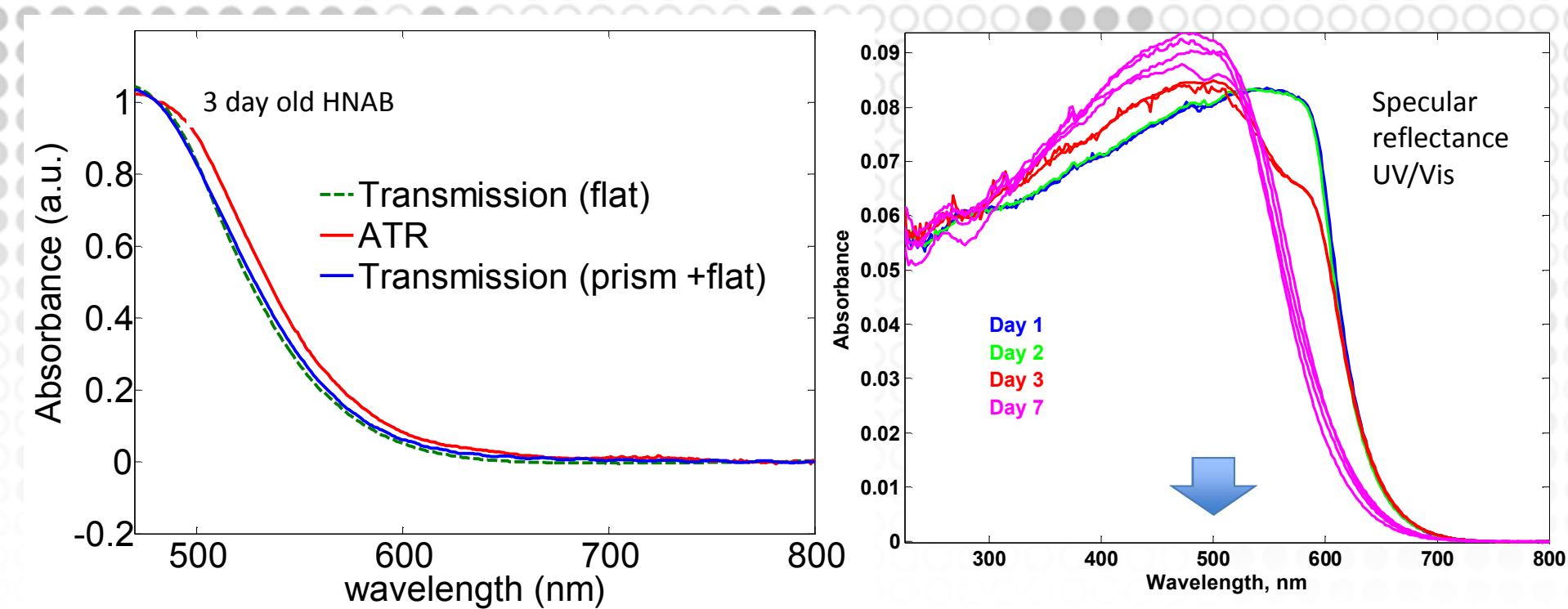
Darcie Farrow¹, Ian Kohl¹, Kathy Alam¹, Laura Martin¹, Stephen Rupper¹, Hongyou Fan¹, Kaifu Bian¹, Robert Knepper¹, Michael Marquez¹, Jeffrey Kay², ¹Sandia National Laboratories, Albuquerque, NM 87185, ²Sandia National Laboratories, Livermore, CA

Motivation

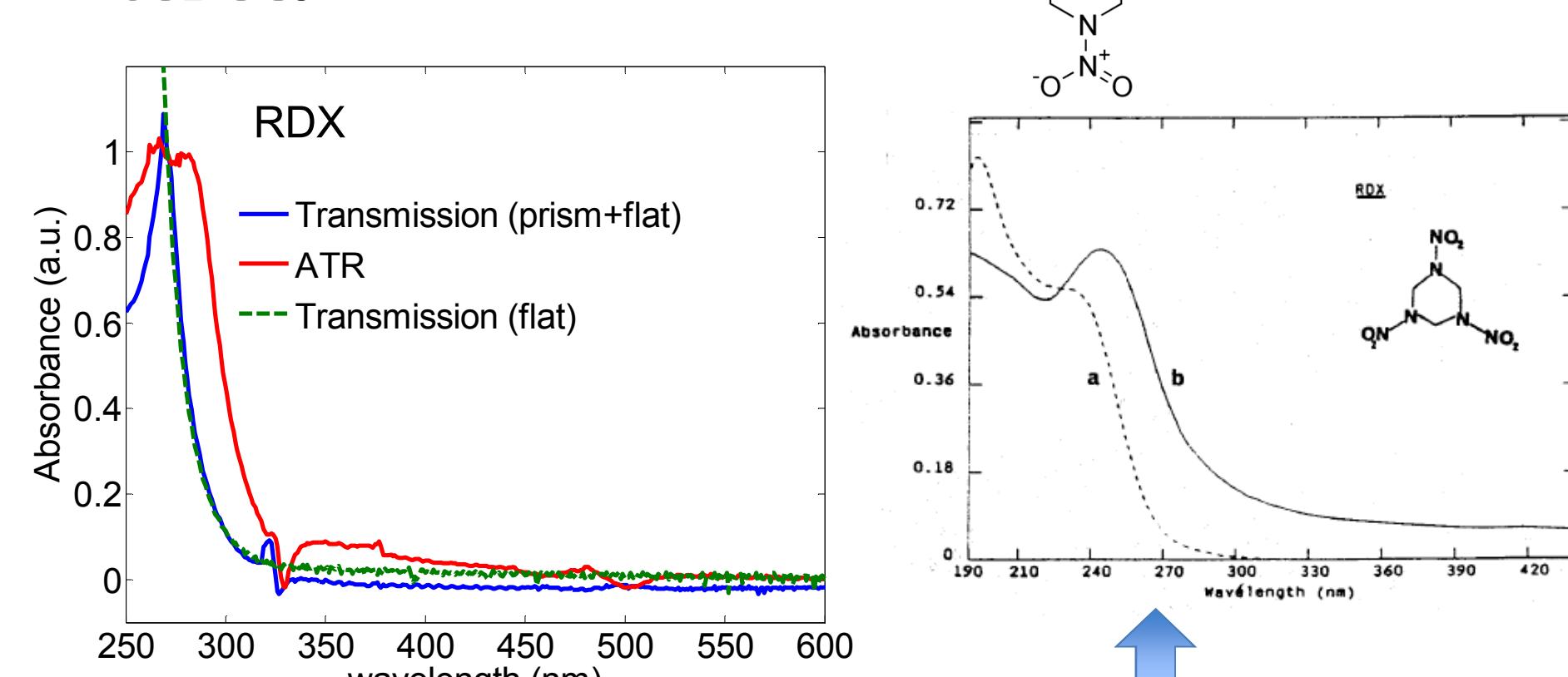


UV/ATR at ambient temperature/pressure

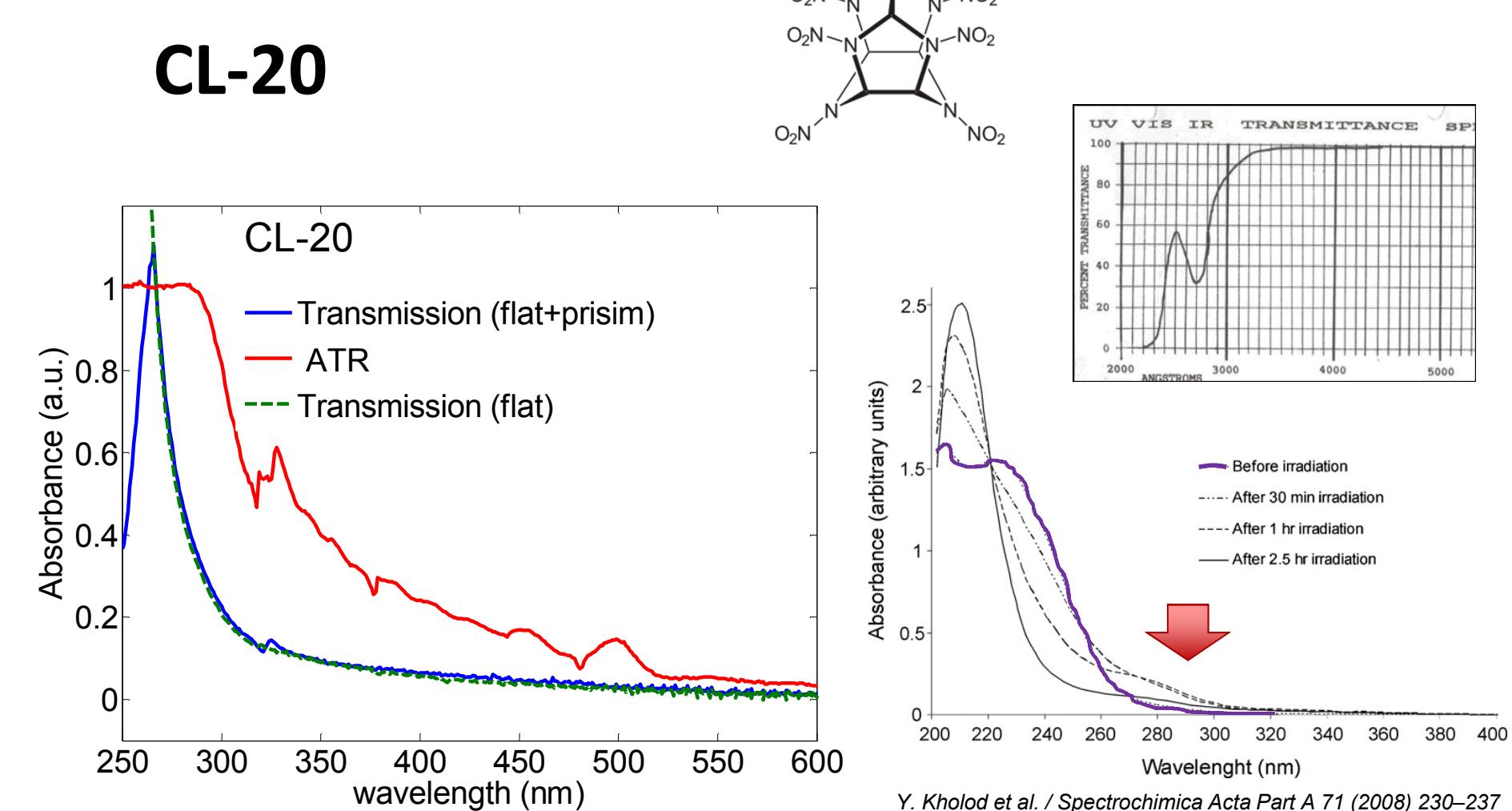
HNAB:



RDX:



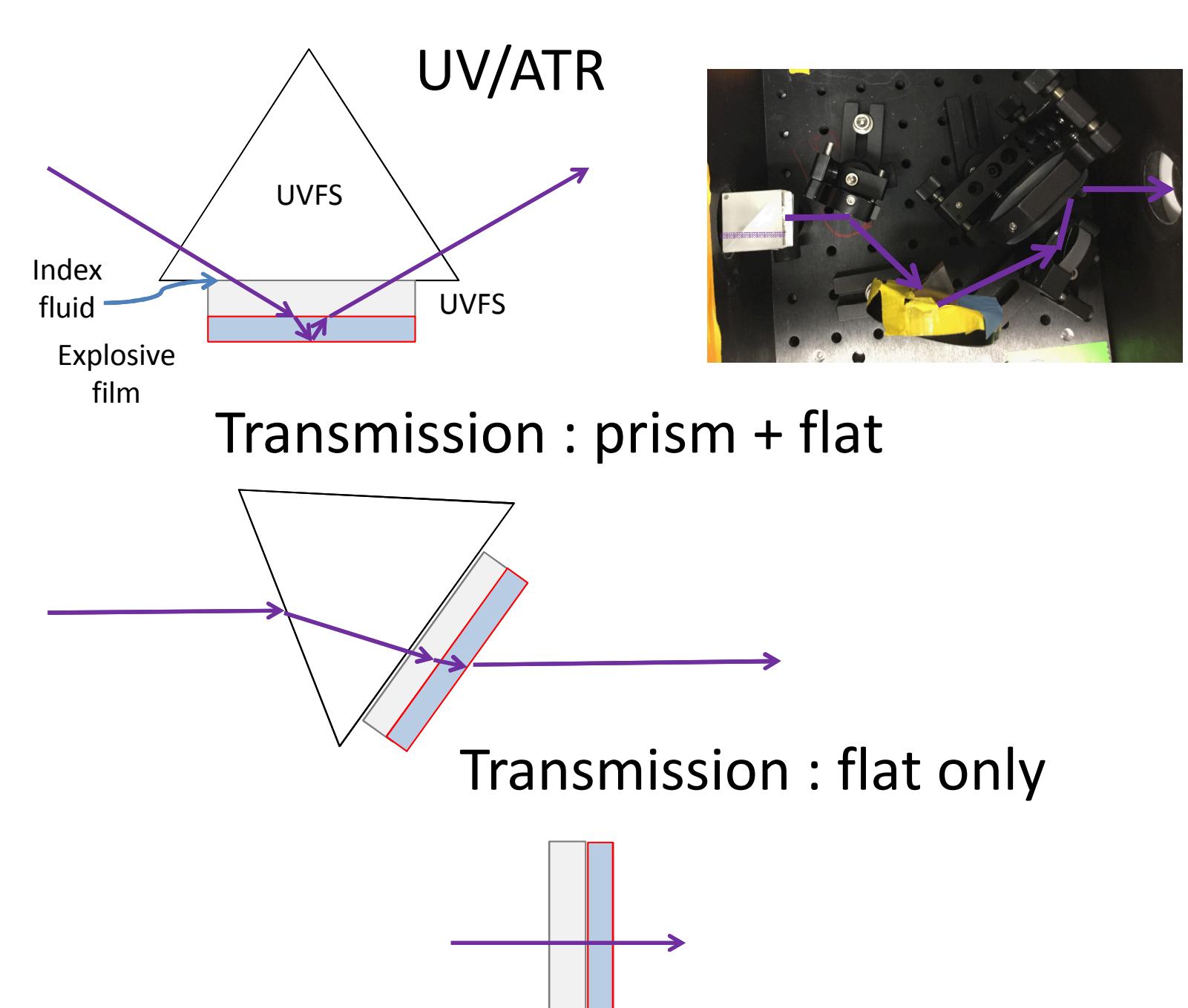
CL-20



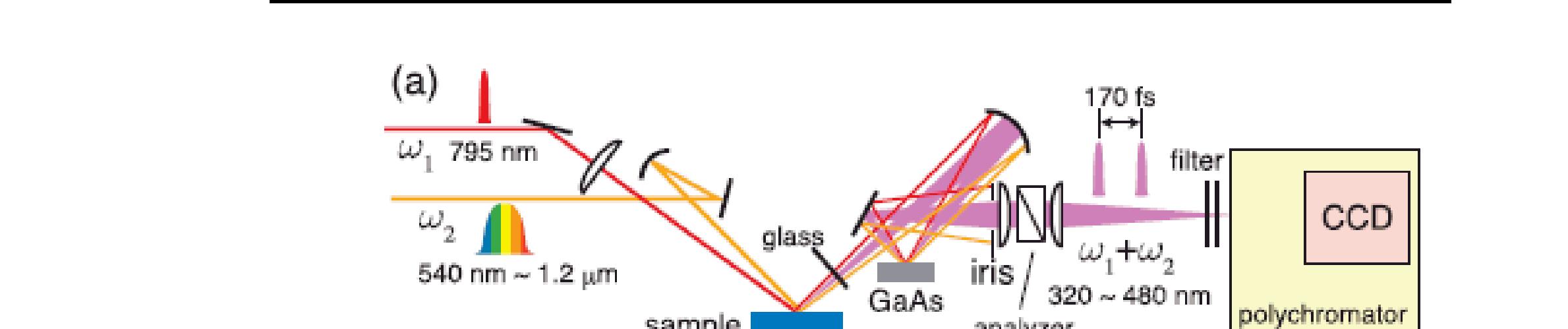
- Significant red-shift in electronic absorption of explosive 10's of nm's from the film surface compared to the bulk film .
- Red shift larger when bulk material band edge is in UV.

Next Step: Surface vs. film spectrum at elevated pressure

UV/ATR at film/air interface



- PerkinElmer Lambda 750 equipped with tungsten-halogen and deuterium sources, with PMT detection.
- Spectra taken of thin film in *transmission* mode through prism/index fluid and of flat/film sample to measure *UV/Vis of bulk film*.
- ATR spectra for UVFS plate with and without thin film explosive. **Red shift and/or change in shape indicate increased surface contribution to spectra.**



- Performing a surface specific spectroscopy (UV/ATR or Electronic Sum Frequency Generation –ESFG) on sample under shock compression or static compression (DAC).
- Compare to TA or UV/Vis data of film under equivalent conditions.
- Use DFT models of material to understand changes in electronic structure in both systems.

